



# HE8051

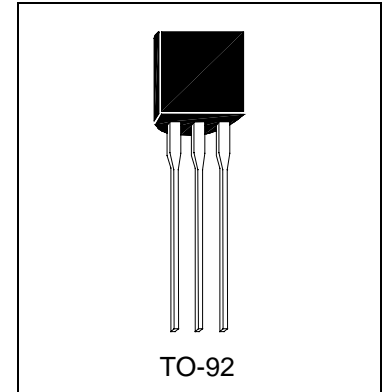
NPN EPITAXIAL PLANAR TRANSISTOR

## Description

The HE8051 is designed for use in 2W output amplifier of portable radios in class B push-pull operation.

## Features

- High Total Power Dissipation ( $P_T$ : 2W,  $T_C=25^\circ\text{C}$ )
- High Collector Current ( $I_C$ : 1.5A)



## Absolute Maximum Ratings

- Maximum Temperatures
  - Storage Temperature ..... -55 ~ +150 °C
  - Junction Temperature ..... +150 °C Maximum
- Maximum Power Dissipation
  - Total Power Dissipation ( $T_A=25^\circ\text{C}$ ) ..... 1 W
- Maximum Voltages and Currents ( $T_A=25^\circ\text{C}$ )
  - $V_{CBO}$  Collector to Base Voltage ..... 40 V
  - $V_{CEO}$  Collector to Emitter Voltage ..... 25 V
  - $V_{EBO}$  Emitter to Base Voltage ..... 6 V
  - $I_C$  Collector Current ..... 1.5 A
  - $I_B$  Base Current ..... 500mA

## Electrical Characteristics ( $T_A=25^\circ\text{C}$ )

| Symbol         | Min. | Typ. | Max. | Unit | Test Conditions                         |
|----------------|------|------|------|------|---|
| $BV_{CBO}$     | 40   | -    | -    | V    | $I_C=100\mu\text{A}$                    |
| $BV_{CEO}$     | 25   | -    | -    | V    | $I_C=2\text{mA}$                        |
| $BV_{EBO}$     | 6    | -    | -    | V    | $I_E=100\mu\text{A}$                    |
| $I_{CBO}$      | -    | -    | 100  | nA   | $V_{CB}=35\text{V}$                     |
| $I_{EBO}$      | -    | -    | 100  | nA   | $V_{EB}=6\text{V}$                      |
| $*V_{CE(sat)}$ | -    | -    | 0.5  | V    | $I_C=0.8\text{A}$ , $I_B=80\text{mA}$   |
| $*V_{BE(sat)}$ | -    | -    | 1.2  | V    | $I_C=0.8\text{A}$ , $I_B=80\text{mA}$   |
| $V_{BE(on)}$   | -    | -    | 1    | V    | $V_{CE}=1\text{V}$ , $I_C=10\text{mA}$  |
| $*h_{FE1}$     | 45   | -    | -    |      | $V_{CE}=1\text{V}$ , $I_C=5\text{mA}$   |
| $*h_{FE2}$     | 85   | -    | 500  |      | $V_{CE}=1\text{V}$ , $I_C=100\text{mA}$ |
| $*h_{FE3}$     | 40   | -    | -    |      | $V_{CE}=1\text{V}$ , $I_C=800\text{mA}$ |
| $f_T$          | 100  | -    | -    | MHz  | $V_{CE}=10\text{V}$ , $I_C=50\text{mA}$ |

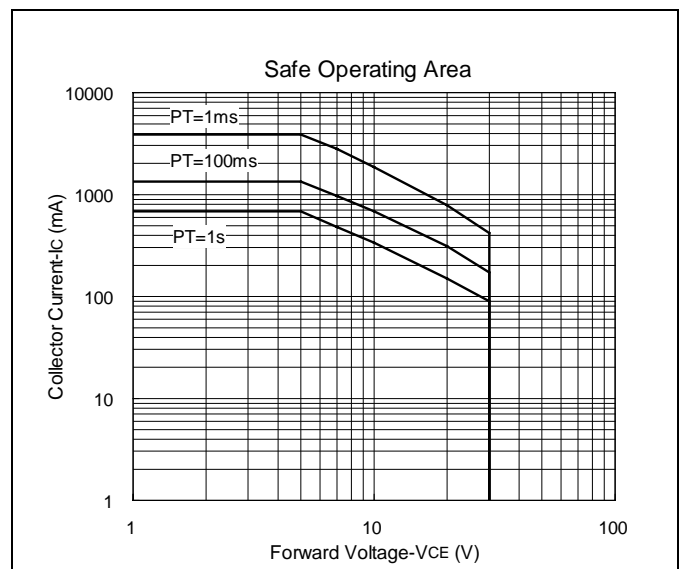
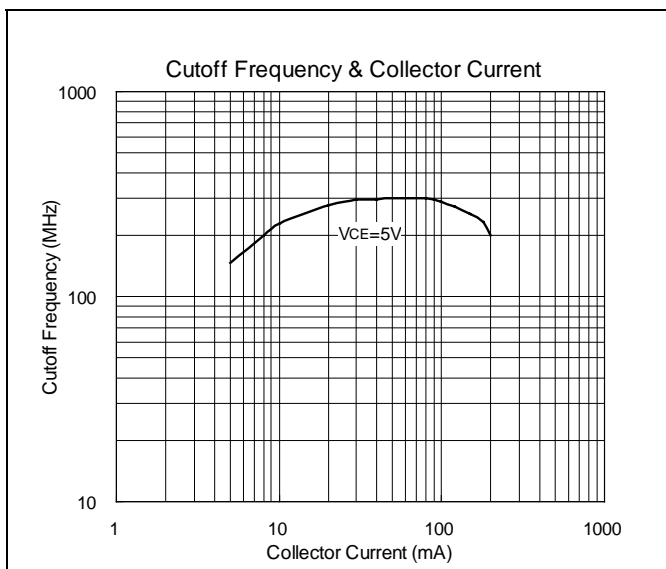
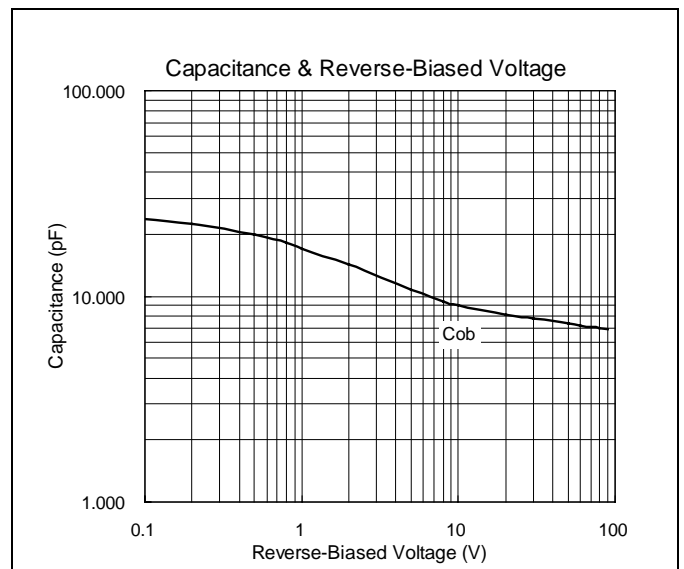
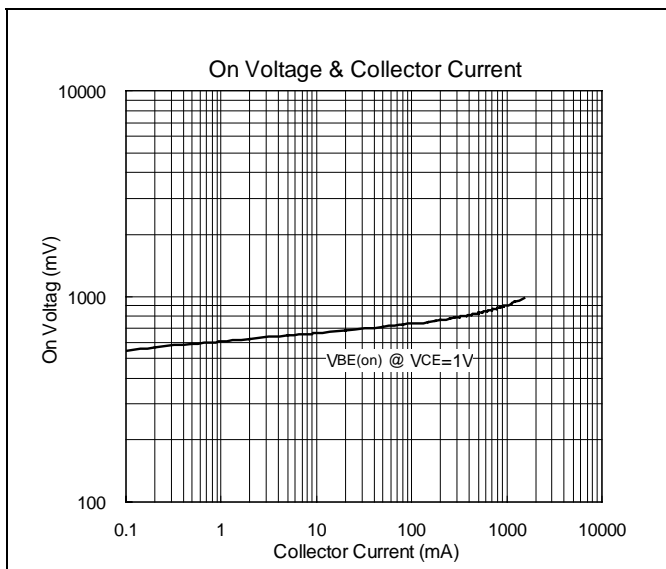
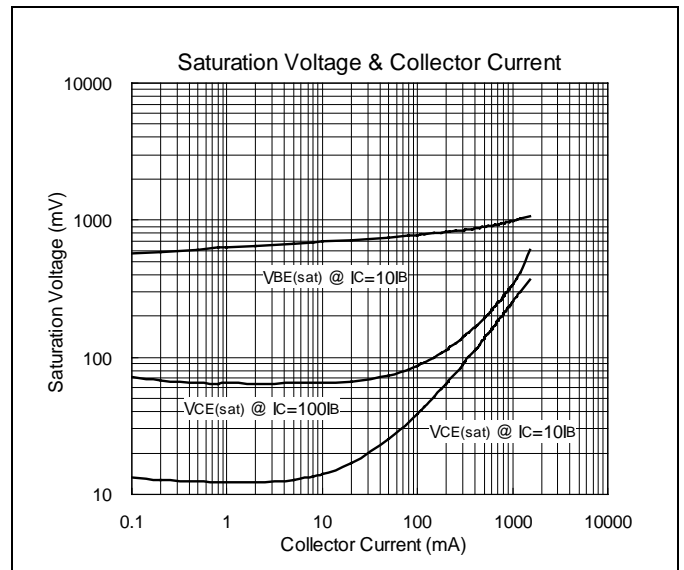
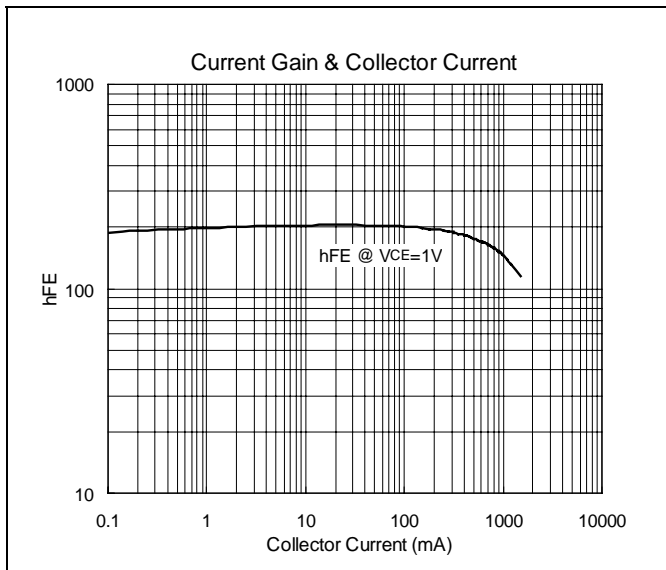
\*Pulse Test: Pulse Width  $\leq 380\mu\text{s}$ , Duty Cycle  $\leq 2\%$

## Classification of hFE2

| Rank  | B      | C       | D       | E       |
|-------|--------|---------|---------|---------|
| Range | 85-160 | 120-200 | 160-300 | 250-500 |



### Characteristics Curve





### TO-92 Dimension

3-Lead TO-92 Plastic Package  
HSMC Package Code: A

**Marking:**

Pb Free Mark  
 Pb-Free: " \* " (Note)  
 Normal: None

Date Code      Control Code

Note: Green label is used for pb-free packing

Pin Style: 1.Emitter 2.Base 3.Collector

Material:

- Lead solder plating: Sn60/Pb40 (Normal), Sn/3.0Ag/0.5Cu or Pure-Tin (Pb-free)
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

| DIM        | Min.  | Max.  |
|------------|-------|-------|
| A          | 4.33  | 4.83  |
| B          | 4.33  | 4.83  |
| C          | 12.70 | -     |
| D          | 0.36  | 0.56  |
| E          | -     | *1.27 |
| F          | 3.36  | 3.76  |
| G          | 0.36  | 0.56  |
| H          | -     | *2.54 |
| I          | -     | *1.27 |
| $\alpha 1$ | -     | *5°   |
| $\alpha 2$ | -     | *2°   |
| $\alpha 3$ | -     | *2°   |

\*: Typical, Unit: mm

### TO-92 Taping Dimension

| DIM   | Min.  | Max.  |
|-------|-------|-------|
| A     | 4.33  | 4.83  |
| D     | 3.80  | 4.20  |
| D1    | 0.36  | 0.53  |
| D2    | 4.33  | 4.83  |
| F1,F2 | 2.40  | 2.90  |
| H     | 15.50 | 16.50 |
| H1    | 8.50  | 9.50  |
| H2    | -     | 1     |
| H2A   | -     | 1     |
| H3    | -     | 27    |
| H4    | -     | 21    |
| L     | -     | 11    |
| L1    | 2.50  | -     |
| P     | 12.50 | 12.90 |
| P1    | 5.95  | 6.75  |
| P2    | 50.30 | 51.30 |
| T     | -     | 0.55  |
| T1    | -     | 1.42  |
| T2    | 0.36  | 0.68  |
| W     | 17.50 | 19.00 |
| W1    | 5.00  | 7.00  |

Unit: mm

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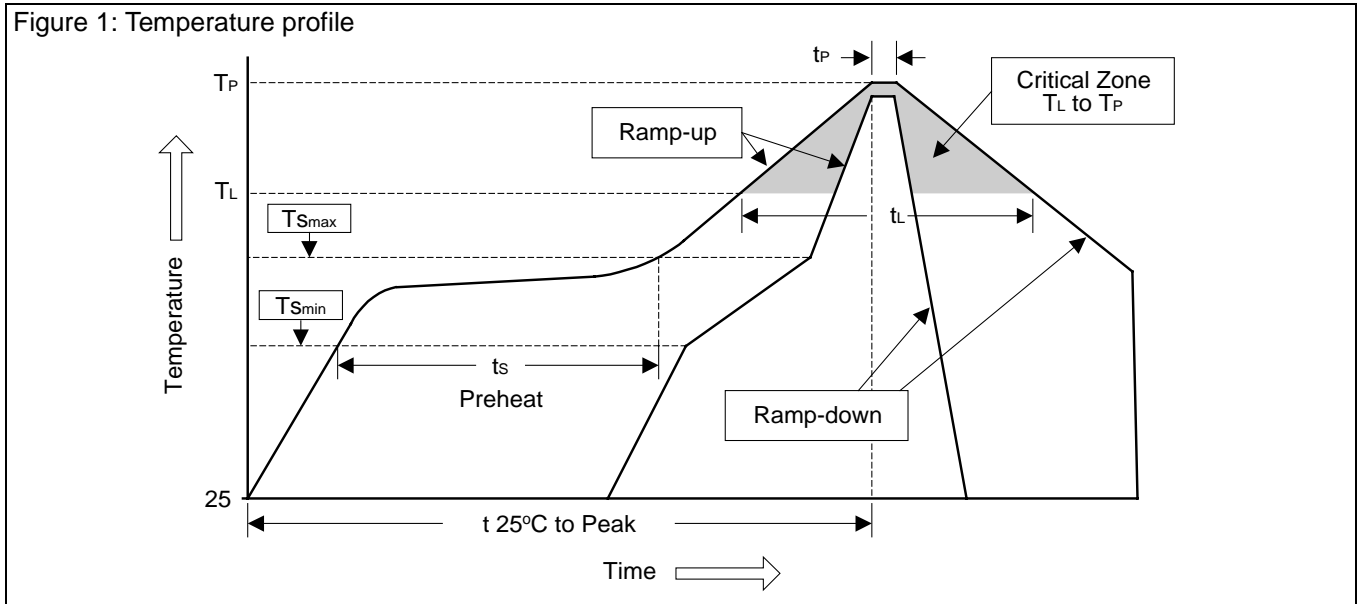
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### Soldering Methods for HSMC's Products

1. Storage environment: Temperature=10°C~35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices

Figure 1: Temperature profile



| Profile Feature                                      | Sn-Pb Eutectic Assembly | Pb-Free Assembly |
|--|-------------------------|------------------|
| Average ramp-up rate ( $T_L$ to $T_P$ )              | <3°C/sec                | <3°C/sec         |
| Preheat  |                         |                  |
| - Temperature Min ( $T_{smin}$ )                     | 100°C                   | 150°C            |
| - Temperature Max ( $T_{smax}$ )                     | 150°C                   | 200°C            |
| - Time (min to max) ( $t_s$ )                        | 60~120 sec              | 60~180 sec       |
| $T_{smax}$ to $T_L$                                  |                         |                  |
| - Ramp-up Rate                                       | <3°C/sec                | <3°C/sec         |
| Time maintained above:                               |                         |                  |
| - Temperature ( $T_L$ )                              | 183°C                   | 217°C            |
| - Time ( $t_L$ )                                     | 60~150 sec              | 60~150 sec       |
| Peak Temperature ( $T_P$ )                           | 240°C +0/-5°C           | 260°C +0/-5°C    |
| Time within 5°C of actual Peak Temperature ( $t_p$ ) | 10~30 sec               | 20~40 sec        |
| Ramp-down Rate                                       | <6°C/sec                | <6°C/sec         |
| Time 25°C to Peak Temperature                        | <6 minutes              | <8 minutes       |

### 3. Flow (wave) soldering (solder dipping)

| Products         | Peak temperature | Dipping time |
|------------------|------------------|--------------|
| Pb devices.      | 245°C ±5°C       | 5sec ±1sec   |
| Pb-Free devices. | 260°C +0/-5°C    | 5sec ±1sec   |